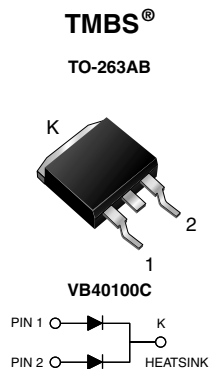


# Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.38 \text{ V}$  at  $I_F = 5 \text{ A}$



## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
FREE

## TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

## PRIMARY CHARACTERISTICS

Package	TO-263AB
$I_{F(AV)}$	2 x 20 A
$V_{RRM}$	100 V
$I_{FSM}$	250 A
$V_F$ at $I_F = 20 \text{ A}$	0.61 V
$T_J \text{ max.}$	150 °C
Diode variation	Common cathode

## MECHANICAL DATA

**Case:** TO-263AB

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

## MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VB40100C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	40	A
		20	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	250	A
Voltage rate of change (rated VR)	$dV/dt$	10 000	V/ $\mu$ s
Operating junction and storage temperature range	$T_J, T_{STG}$	- 40 to + 150	°C

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.47	-	V
	I <sub>F</sub> = 10 A			0.54	-	
	I <sub>F</sub> = 20 A			0.67	0.73	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.38	-	
	I <sub>F</sub> = 10 A			0.45	-	
	I <sub>F</sub> = 20 A			0.61	0.67	
Reverse current at rated V <sub>R</sub> per diode <sup>(2)</sup>	V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	9	-	μA
		T <sub>A</sub> = 125 °C		10	-	mA
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C		-	1000	μA
		T <sub>A</sub> = 125 °C		21	45	mA

**Notes**
<sup>(1)</sup> Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq 40\text{ ms}$ 

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VB40100C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	$^{\circ}\text{C/W}$

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB40100C-M3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40100C-M3/8W	1.39	8W	800/reel	Tape and reel

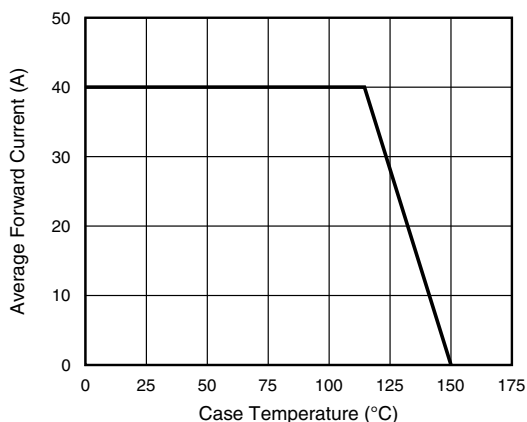
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

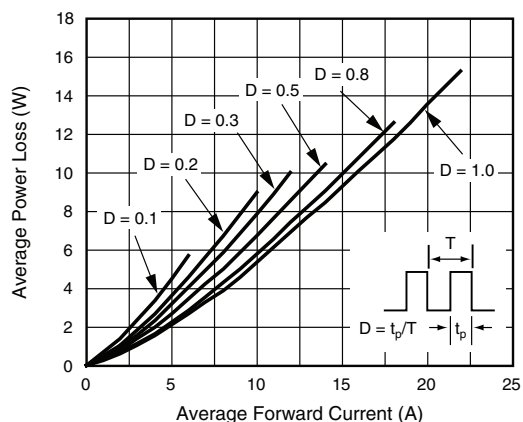


Fig. 2 - Forward Power Loss Characteristics Per Diode

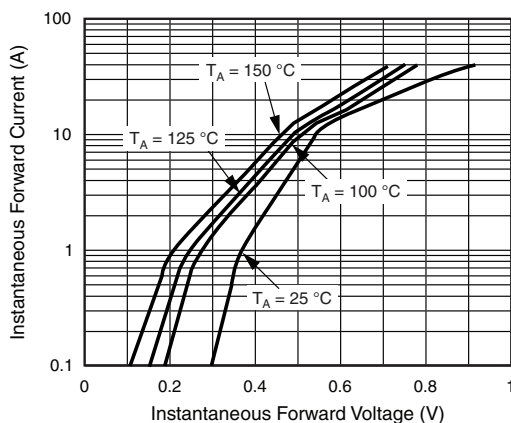


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

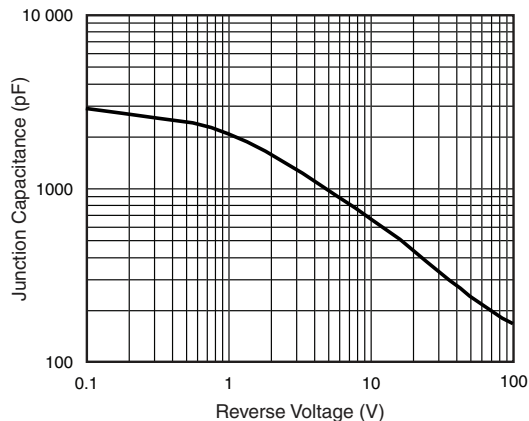


Fig. 5 - Typical Junction Capacitance Per Diode

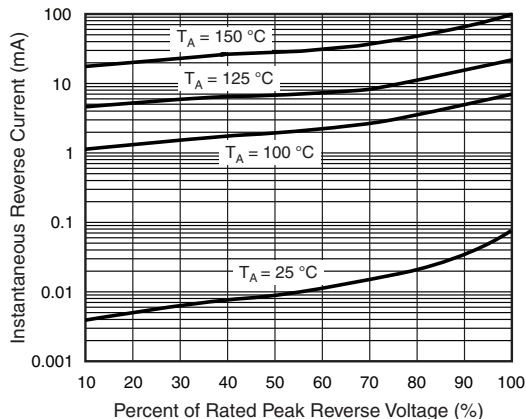


Fig. 4 - Typical Reverse Characteristics Per Diode

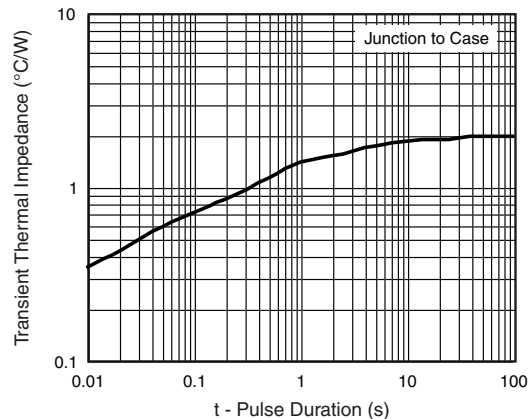
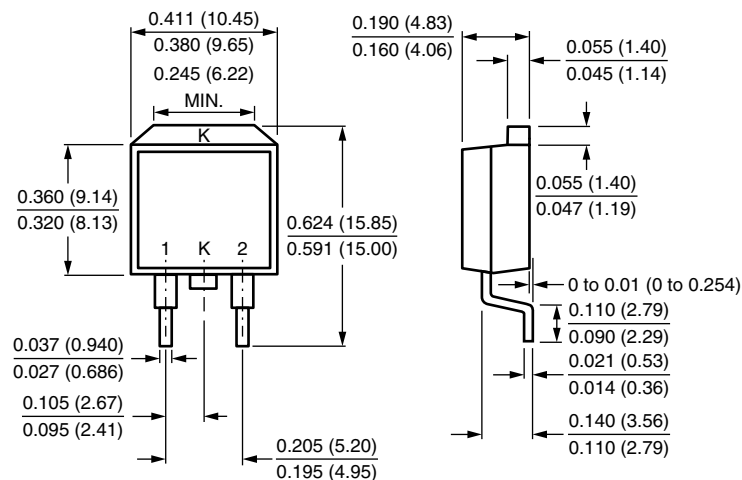


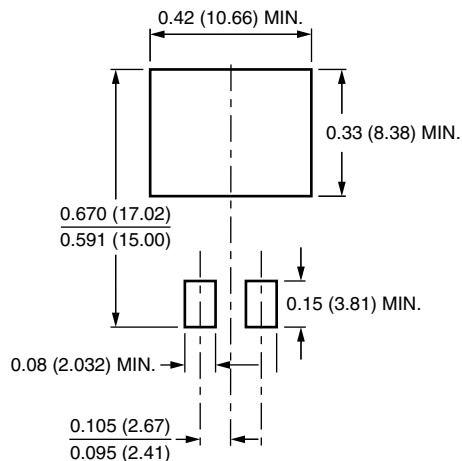
Fig. 6 - Typical Transient Thermal Impedance Per Diode

## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-263AB



### Mounting Pad Layout





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